

MMSTA13-7-F Datasheet



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DiGi Electronics Part Number	MMSTA13-7-F-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	MMSTA13-7-F
Description	TRANS NPN DARL 30V 0.3A SOT323
Detailed Description	Bipolar (BJT) Transistor NPN - Darlington 30 V 300 mA 125MHz 200 mW Surface Mount SOT-323



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Purchase and inquiry

Manufacturer Product Number:

MMSTA13-7-F

Series:

-

Transistor Type:

NPN - Darlington

Voltage - Collector Emitter Breakdown (Max):

30 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

200 mW

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

SC-70, SOT-323

Base Product Number:

MMSTA13

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

300 mA

Vce Saturation (Max) @ Ib, Ic:

1.5V @ 100µA, 100mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

10000 @ 100mA, 5V

Frequency - Transition:

125MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-323

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



MMSTA13/MMSTA14

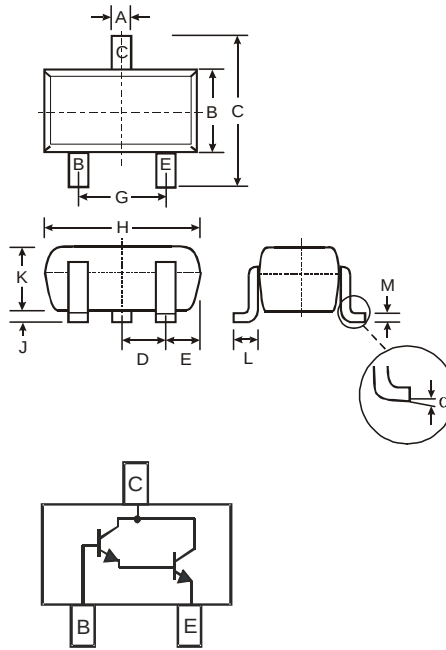
NPN SURFACE MOUNT DARLINGTON TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMSTA63/MMSTA64)
- Ideal for Low Power Amplification and Switching
- High Current Gain
- Ultra-Small Surface Mount Package
- **Lead Free/RoHS Compliant (Note 2)**
- **"Green" Device (Note 3 and 4)**

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMSTA13 Marking K2D, K3D, See Page 3
- MMSTA14 Marking K3D, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
α	0°	8°
All Dimensions in mm		

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	30	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	10	V
Collector Current - Continuous (Note 1)	I _C	300	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
2. No purposefully added lead.
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	30	—	V	I _C = 100μA V _{BE} = 0V
Collector Cutoff Current	I _{CBO}	—	100	nA	V _{CB} = 30V, I _E = 0
Emitter Cutoff Current	I _{EBO}	—	100	nA	V _{EB} = 10V, I _C = 0
ON CHARACTERISTICS (Note 5)					
DC Current Gain	MMSTA13 MMSTA14 MMSTA13 MMSTA14	h _{FE}	5,000 10,000 10,000 20,000	—	I _C = 10mA, V _{CE} = 5.0V I _C = 10mA, V _{CE} = 5.0V I _C = 100mA, V _{CE} = 5.0V I _C = 100mA, V _{CE} = 5.0V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	1.5	V	I _C = 100mA, I _B = 100μA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	2.0	V	I _C = 100mA, V _{CE} = 5.0V
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	8.0 Typical		pF	V _{CB} = 10V, f = 1.0MHz, I _E = 0
Input Capacitance	C _{ibo}	15 Typical		pF	V _{EB} = 0.5V, f = 1.0MHz, I _C = 0
Current Gain-Bandwidth Product	f _T	125	—	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 100MHz

Note: 5. Short duration pulse test used to minimize self-heating effect.

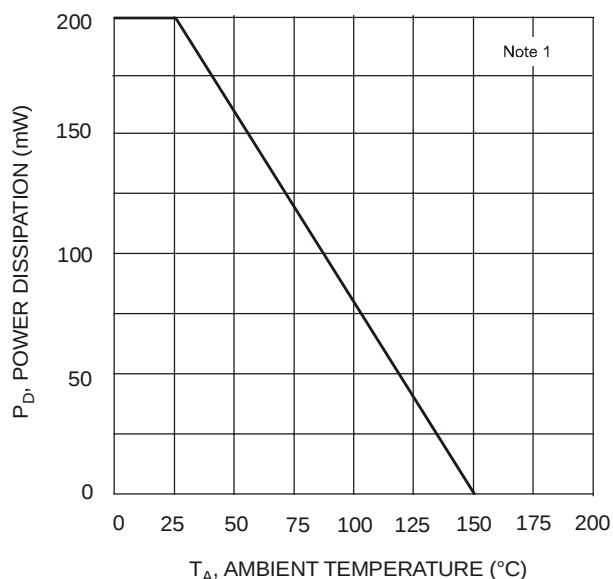


Fig. 1, Max Power Dissipation vs. Ambient Temperature

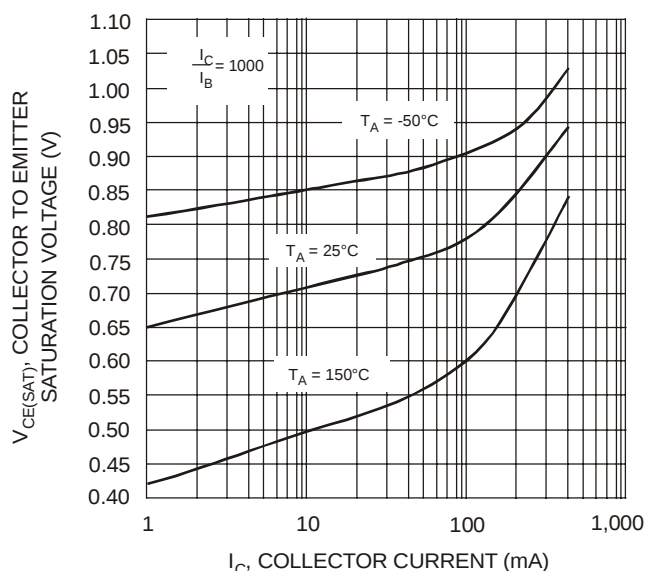


Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current

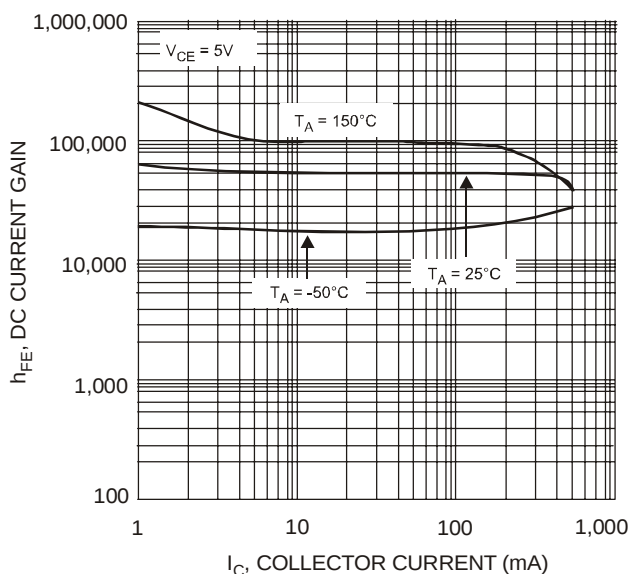


Fig. 3, DC Current Gain vs. Collector Current

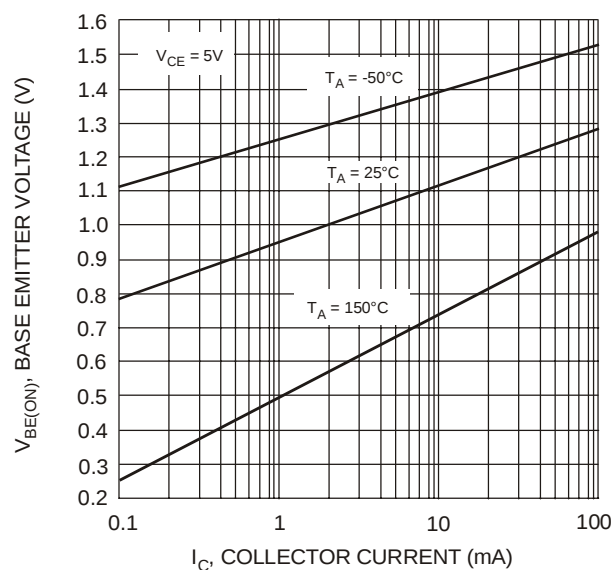


Fig. 4, Base Emitter Voltage vs. Collector Current

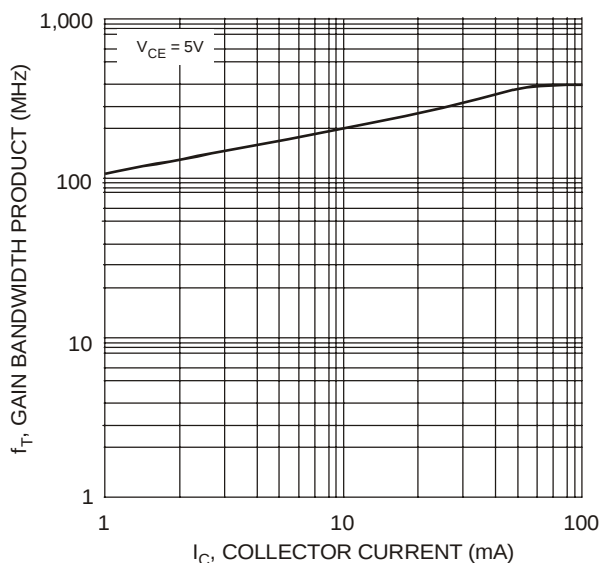


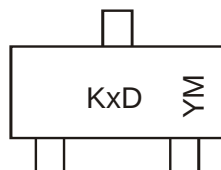
Fig. 5, Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 4 & 6)

Device	Packaging	Shipping
MMSTA13-7-F	SOT-323	3000/Tape & Reel
MMSTA14-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



KxD = Product Type Marking Code, e.g., K2D = MMSTA13

YM = Date Code Marking

Y = Year ex: N = 2002

M = Month ex: 9 = September

Date Code Key

Year	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	L	M	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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